

LOW NOISE BOARD STACKER FTW SERIES

Mates with:
CLT, SQT, ESQT, TLE,
SMM, MMS, TCSD

For prototype quantities only. Call Samtec for production volume Ferrite shielding.

Features:

- Low or high impedance ceramic insulators on each pin
- Wide range of board spacing achievable
- Through-hole and Surface Mount
- Single and double row

Specifications:

FTW

Insulator Material:

Black LCP and Gray Ferrite

Terminal Material:

Phosphor Bronze

Current Rating:

3A @ 80°C ambient

Operating Temp Range:

-65°C to 125°C with Gold

-65°C to 105°C with Tin

Plating:

Au or Sn over

50µ" (1,27µm) Ni

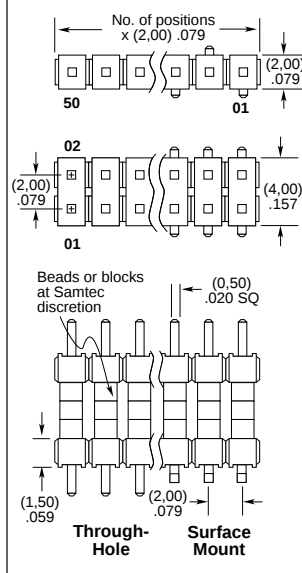
SMT Lead Coplanarity:

(0,15mm) .006" max

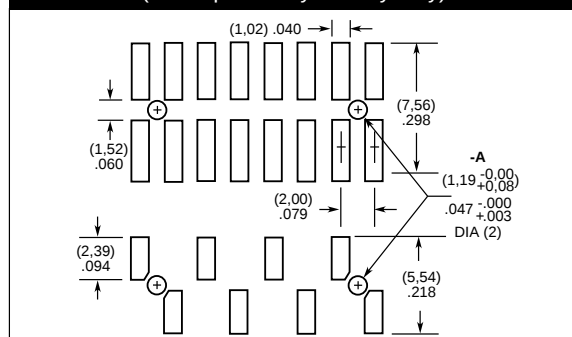
Note:

This Series is non-standard, non-returnable.

FTW	NO. PINS PER ROW	LEAD STYLE	PLATING OPTION	ROW OPTION	FREQUENCY OPTION	TAIL OPTION
02 thru 50 =Through-Hole	02 thru 36 =Surface Mount	- G = 20µ" (0,51µm) Gold post area of longer tail Gold flash on tail	- S = 30µ" (0,76µm) Gold post 150µ" (3,81µm) Tin on tail Style -02 not available.	- S = Single Row	- L = Low Frequency (EMI suppression < 30 MHz)	- SM = Surface Mount
		- T = 150µ" (3,81µm) Tin				
		APPLICATION SPECIFIC OPTIONS				
Alignment pins and locking clips available. Call Samtec.						

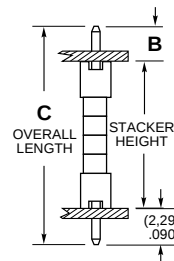


SUGGESTED PCB LAYOUTS (Your specific layout may vary)



Specify LEAD STYLE from chart

LEAD STYLE	C		B	STACKER HEIGHT	IMPEDANCE			
					FREQ	10MHz	25MHz	100MHz
-02	(9,58)	(3,77)	(2,72)	(4,57)	LOW	4.4Ω min	7.5Ω ±20%	—
					HIGH	—	4.4Ω min	14Ω ±20%
-03	(13,60)	(5,35)	(2,16)	(9,14)	LOW	17.6Ω min	30Ω ±20%	—
					HIGH	—	17.6Ω min	56Ω ±20%
-04	(15,10)	(5,94)	(2,13)	(10,67)	LOW	22Ω min	37.5Ω ±20%	—
					HIGH	—	22Ω min	70Ω ±20%



LEAD STYLE	C		STACKER HEIGHT	IMPEDANCE			
				FREQ	10MHz	25MHz	100MHz
-02	(8,08)	(3,18)	(6,30)	LOW	4.4Ω min	7.5Ω ±20%	—
				HIGH	—	4.4Ω min	14Ω ±20%
-03	(11,13)	(4,38)	(9,35)	LOW	13.2Ω min	22.5Ω ±20%	—
				HIGH	—	13.2Ω min	42Ω ±20%
-04	(12,65)	(4,98)	(10,87)	LOW	17.6Ω min	30Ω ±20%	—
				HIGH	—	17.6Ω min	56Ω ±20%
-05	(15,70)	(6,18)	(13,92)	LOW	26.4Ω min	45Ω ±20%	—
				HIGH	—	26.4Ω min	84Ω ±20%

